

Description

The HTH8G07P600H(B) is an unmatched discrete LDMOS Power Amplifier with 600W saturated output power covering frequency range from 1.8 - 700 MHz.

Features

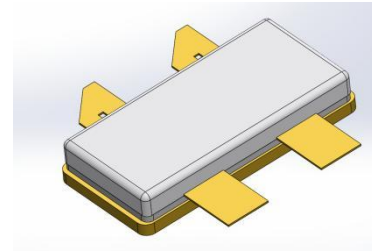
- Operating Frequency Range: 1.8 - 700 MHz
- Operating Drain Voltage: +50V
- Saturation Output Power: 600W
- Internally Unmatched device
- Excellent thermal stability due to low thermal resistance package
- Enhanced robustness design without device degradation
- Internally integrated enhanced ESD design

Applications

- Analog and Digital Broadcasting
- Meteorological and Aviation Radar
- Private network communication base station
- Industrial Scientific Medical (ISM)
 - Laser generation
 - Plasma generation
 - Particle accelerators
 - MRI, RF ablation and skin treatment
 - Industrial heating, welding and drying systems

Ordering Information

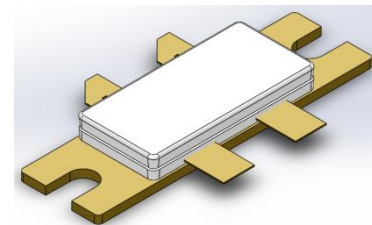
Part Number	Description
HTH8G07P600H(B)	Tray Package
HTH8G07P600H(B) EVB	470 - 700 MHz EVB



ACC2110S-4L



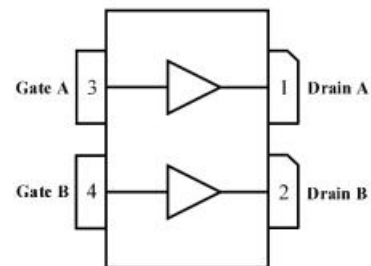
Earless Flanged balanced
Air Cavity Ceramic Package; 4 Leads
HTH8G07P600H



ACC2110B-4L



Flanged balanced
Air Cavity Ceramic Package; 4 Leads,
2 Mounting holes
HTH8G07P600HB



(Top View)

Note: Exposed backside of the package is the source terminal for the transistor

Pin Connections

Typical Performance

RF Characteristics (Pulsed-CW)

Freq (MHz)	Gain(dB)	P1dB (dBm)	Eff(%) @P1dB	P3dB (dBm)	Eff(%) @P3dB
470	23.9	57.8	53.5	58.5	55.5
500	23.9	58.0	59.0	58.5	60.1
550	23.0	57.4	61.9	58.4	66.5
600	21.9	56.8	63.7	57.5	65.5
650	22.0	56.7	59.5	57.4	61.1
700	22.0	57.0	60.9	57.7	62.1

Test conditions unless otherwise noted: 25 °C, VDD = +50Vdc, IDQ =500mA, PW = 100us, DC= 10% test on WATECH Application Board

Absolute Maximum Ratings

Parameter	Range/Value	Unit
Drain voltage (V _{DSS})	-0.5 to +110	V
Gate voltage (V _{GS})	-5 to +10	V
Operating Voltage (V _{DS})	0 to +50	V
Storage Temperature (T _{STG})	-55 to +150	°C
Junction Temperature (T _J)	-40 to +225	°C

Electrical Specification

DC Characteristics

Parameter	Conditions	Min	Typ	Max	Unit
Breakdown Voltage V _{(BR)DSS}	V _{gs} =0V, I _{ds} =180uA	110	-	-	V
Gate-Source Threshold Voltage V _{GS(th)}	V _{ds} =10V, I _{ds} =180uA	-	2.2	-	V
Drain Leakage Current I _{DSS}	V _{gs} =0V, V _{ds} =110V	-	-	10	uA
Gate Leakage Current I _{GSS}	V _{gs} =10V, V _{ds} =0V	-	-	1	uA

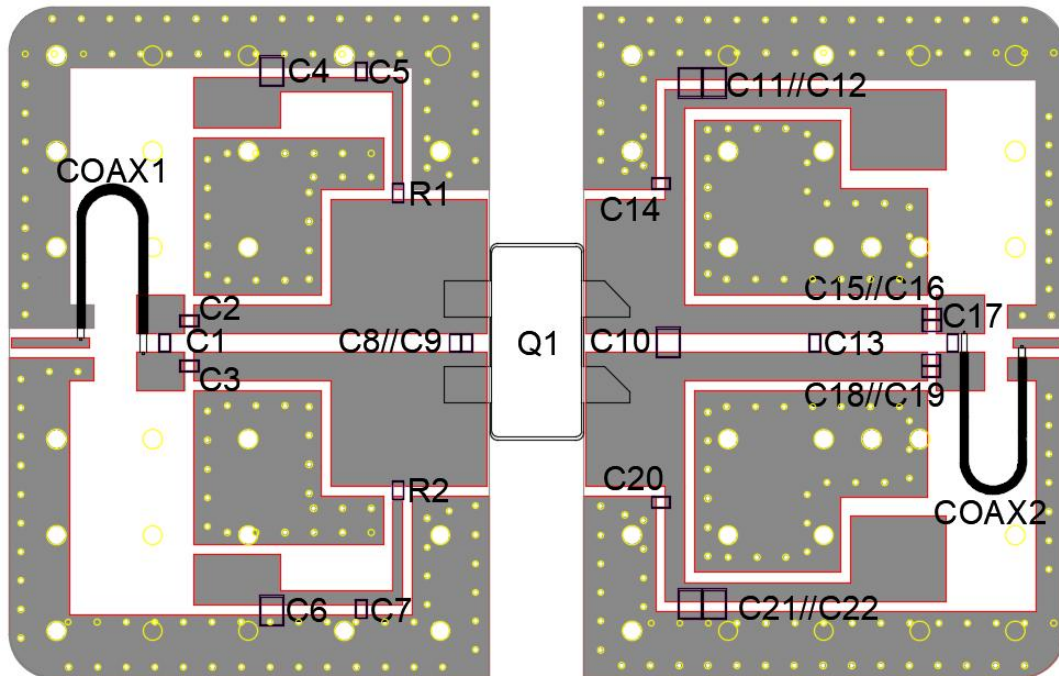
Load Mismatch Test

Condition	Test Result
VDD=50V, IDQ=500mA, Freq=470MHz, PL=600W, Pulse Signal, VSWR 10:1	No Device Degradation

Thermal Information

Parameter	Condition	Value (Typ)	Unit
Thermal Resistance Junction to Case (R _{TH})	VDD=50V, IDQ=500mA, Tcase=25 °C, Pulse Signal, Pout=49dBm (Pavg 39dBm)	0.6	°C /W

HTH8G07P600H(B) 470-700 MHz Reference Design



EVB Layout

Bill of Materials (BoM) - HTH8G07P600H(B) 470 - 700 MHz Reference Design

Reference	Value	Description	Manufacturer	P/N
Q1	-	LDMOS Power Transistor	Watech	HTH8G07P600H(B)
C1	10pF	10pF Chip Capacitor	Murata	GQM2195C2E100JB12
C2,C3,C5,C7,C14, C15,C16,C18,C19, C20	100pF	100pF Chip Capacitors	Murata	GQM2195C2E101JB12D



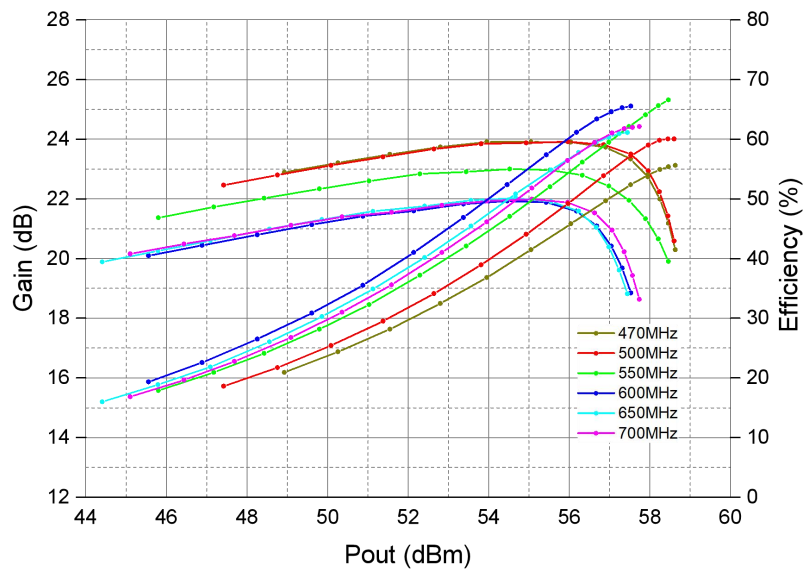
HTH8G07P600H(B)

600W, 1.8 - 700 MHz LDMOS Amplifier

Product datasheet

C4,C6,C12,C22	4.7uF	4.7uF Chip Capacitors	Murata	GCM32DC72A475KE02L
C8	18pF	18pF Chip Capacitors	Murata	GQM2195C2E180JB12
C9	22pF	22pF Chip Capacitors	Murata	GQM2195C2E220JB12
C10	39pF	39pF Chip Capacitors	ATC	ATC800B390FT500XT
C11,C21	1nF	1nF Chip Capacitors	Murata	GRM3195C2A102JA01D
C13	9pF	9pF Chip Capacitors	Murata	GQM2195G2E9R0BB12
C17	3.9pF	3.9pF Chip Capacitors	Murata	GQM2195G2E3R9BB12
COAX1,COAX2		50Ohm Coax, 110 mm	Arbitrary	Arbitrary
PCB	Rogers4350B(er=3.5), 20mil,35 μm (1oz)			

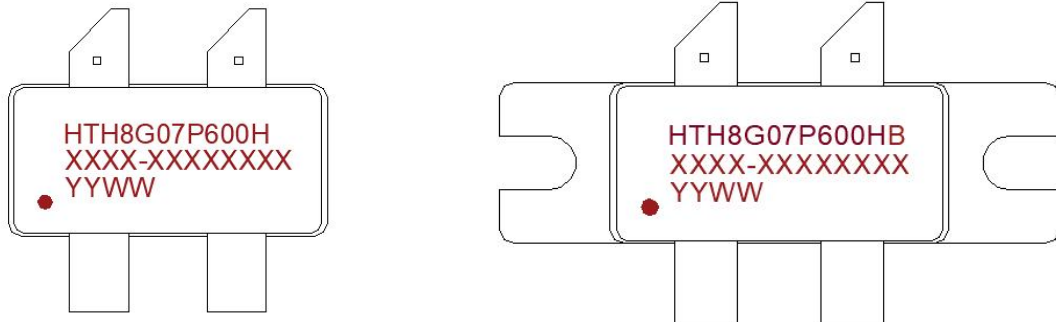
Performance Plots



Pulsed CW, Gain and Efficiency vs Pout

Test conditions unless otherwise noted: 25 °C, VDD = +50dc, IDQ= 500mA, PW = 1000us, DC= 10% test on WATECH Application Board

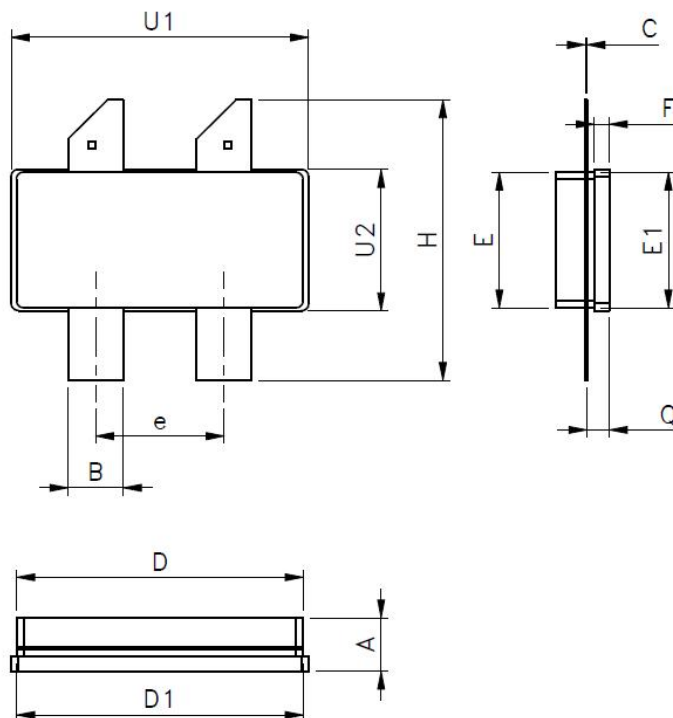
Package Marking and Dimensions



- Line1 (fixed): Device name in W/O
- Line2 (unfixed): Marking Lot No in W/O (Sample: E596-EERA0001)
- Line3 (unfixed): Date Code

This Marking SPEC only stipulates the content of Marking. For marking requirements such as font and size, please refer to the latest version of “Watech Product Printing Specification”

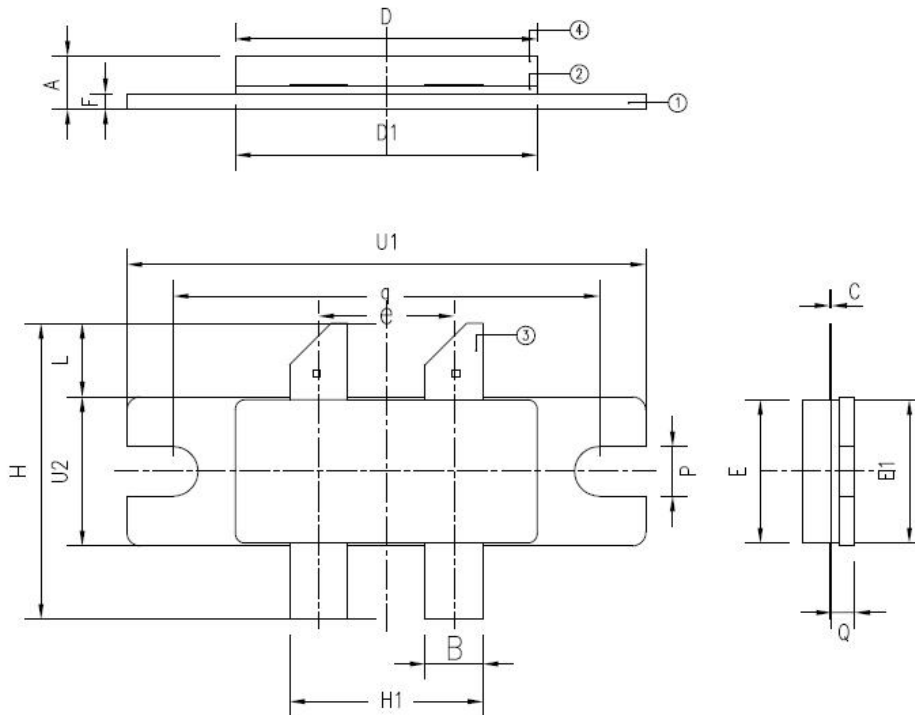
Marking



Symbol	Dimensions in Millimeters			Dimensions in Inches		
	Min.	Mon.	Max.	Min.	Mon.	Max.
A	3.12	3.69	4.26	0.123	0.145	0.168
B	3.69	3.81	3.93	0.145	0.150	0.155
C	-	0.11	-	-	0.004	-
D	19.61	19.81	20.01	0.772	0.780	0.788
D1	19.66	19.81	19.96	0.774	0.780	0.786
E	9.273	9.4	9.527	0.365	0.370	0.375
E1	9.28	9.4	9.52	0.365	0.370	0.375
F	0.95	1.02	1.09	0.037	0.040	0.043
H	19.38	19.43	19.48	0.763	0.765	0.767
Q	1.46	1.53	1.6	0.057	0.060	0.063
U1	20.51	20.58	20.65	0.807	0.810	0.813
U2	9.71	9.78	9.85	0.382	0.385	0.388
e	8.77	8.89	9.01	0.345	0.350	0.355

Package Dimensions

ACC2110S-4L Earless Flanged Ceramic Package; 4 leads





HTH8G07P600H(B) 600W, 1.8 - 700 MHz LDMOS Amplifier

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Symbol	Dimesions in Milimeters			Dimesions in Inches		
	Min.	Mon.	Max.	Min.	Mon.	Max.
A	3.55	3.71	3.86	0.140	0.146	0.152
B	3.68	3.81	3.94	0.145	0.150	0.155
C	0.04	0.11	0.18	0.002	0.004	0.007
D	19.61	19.81	20.01	0.772	0.780	0.788
D1	19.61	19.81	20.01	0.772	0.780	0.788
E	9.28	9.40	9.52	0.365	0.370	0.375
E1	9.28	9.40	9.52	0.365	0.370	0.375
F	0.95	1.02	1.09	0.037	0.040	0.043
H	18.93	19.43	19.93	0.745	0.765	0.785
H1	12.57	12.70	12.83	0.495	0.500	0.505
L	4.71	4.83	4.95	0.185	0.190	0.195
P	3.12	3.25	3.38	0.123	0.128	0.133
Q	1.43	1.53	1.63	0.056	0.060	0.064
q	-	27.94	-	-	1.10	-
U1	33.91	34.04	34.16	1.335	1.340	1.345
U2	9.71	9.78	9.85	0.382	0.385	0.388
e	-	8.89	-	-	0.35	-

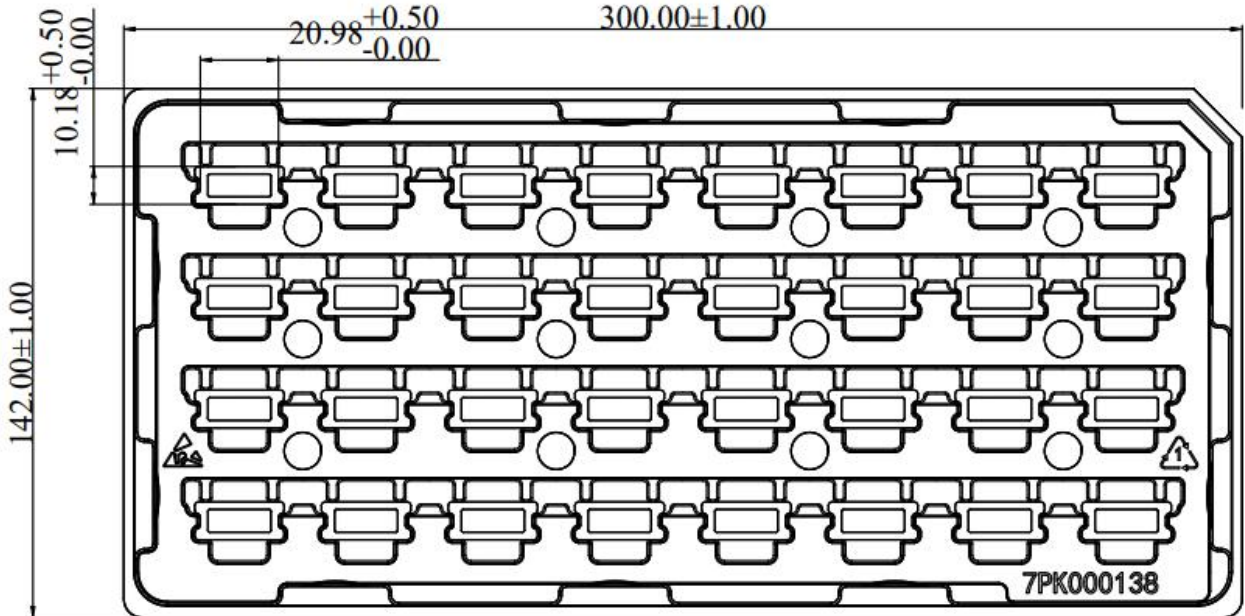
Package Dimensions

ACC2110B-4L Flanged Ceramic Package; 2 mounting holes; 4 leads

Packing Information

HTH8G07P600H:

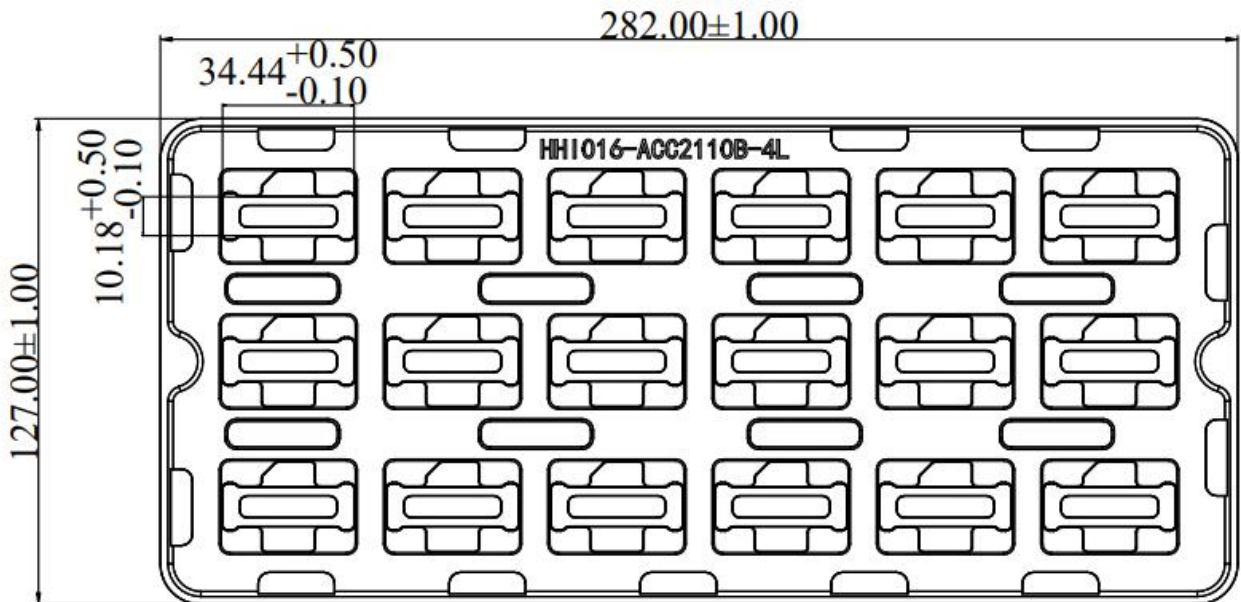
Package Type	Qty/Tray(pcs)	Qty/Box(pcs)	Qty/Carton(pcs)
ACC2110S-4L	32	160	960



Tray Packaging Descriptions

HTH8G07P600HB:


Package Type	Qty/Tray(pcs)	Qty/Box(pcs)	Qty/Carton(pcs)
ACC2110B-4L	18	90	540



Tray Packaging Descriptions

Handling Precautions

Parameter	Grade
Moisture Sensitivity Level MSL	3

Parameter	Rating	Standard	
ESD – Human Body Model (HBM)	Class 1B	JESD22-A114	
ESD – Human Body Model (MM)	Class A	EIA/JESD22-A115	
ESD – Charged Device Model (CDM)	Class III	JESD22-C101	

RoHS Compliance

This product is compliant with the 2011/65/EU RoHS directive (Restrictions on the Use of Certain Hazardous Substances in Electrical and Electronic Equipment), as amended by Directive 2015/863/EU.

Datasheet Status

Document status	Product status	Definition
Objective Datasheet	Design simulation	Product objective specification
Preliminary Datasheet	Customer sample	Engineering samples and first test results
Product Datasheet	Mass production	Final product specification

Abbreviations

Acronym	Definition
LDMOS	Laterally-Diffused Metal-Oxide Semiconductor
CW	Continuous Waveform



HTH8G07P600H(B)

600W, 1.8 - 700 MHz LDMOS Amplifier

Product datasheet

Revision history

Document ID	Datasheet Status	Release Date	Revision Version
Rev 0.1	Preliminary	August 2021	Initial version
Rev 0.2	Preliminary	August 2021	Correct package HTH8G07P600HB picture
Rev 0.3	Preliminary	March 2023	New format based on English version datasheet
Rev 1.0	Product	Sept. 2023	Update TBD information
Rev 1.1	Product	Dece. 2023	Update Frequency information
Rev 1.2	Product	March 2024	Version released after re review
Rev 1.3	Product	June 2024	Update EVB layout design
Rev 1.4	Product	August 2024	Update package information



HTH8G07P600H(B) 600W, 1.8 - 700 MHz LDMOS Amplifier

Product datasheet

Contact Information

For the latest specifications, additional product information, worldwide sales and distribution locations and information about WATECH:

- Web: www.watechelectronics.com
- Email: MKT@huatai-elec.com

For technical questions and application information:

- Email: MKT@huatai-elec.com

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